

EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	566	372/41.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 10:02
L2	3	1 and passivation	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 10:02
L3	1738	372/43.01.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 10:17
L4	512	3 and nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 10:17
L5	691	372/44.01.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 10:30
L6	169	5 and nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 10:30
L7	2101	372/46.01.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 10:51
L8	550	7 and (passivation or nitride)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 10:52
L9	1587	372/50.1.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:05
L10	428	9 and (passivation or nitride)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:06
L11	189	372/54.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:17

L12	949	372/81.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:22
L13	12	12 and nitride	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:22
L14	254	12 and semiconductor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:23
L15	142	((kwang near3 ki near3 choi) or (joon near3 kwak)).in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:35
L16	4	15 and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:36
L17	10	15 and corner	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:37
L18	9	15 and rounded	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO	OR	ON	2010/10/11 11:37
S1	16	semiconductor near3 laser same round\$3 near3 corner \$1	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 20:27
S2	18	semiconductor near3 laser and round\$3 near3 corner \$1 and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 19:27
S3	10	semiconductor near3 laser and curv\$6 near3 corner\$1 and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 19:31
S4	10	(scrib\$3 near3 force near3 (prevent\$3 or suppression or attenuation or reduc\$4 or eliminat\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 20:49
S5	2	((("4476563") or ("5966396")).PN.	US-PGPUB; USPAT	OR	OFF	2006/10/31 19:34

S6	13	("20010015448" "20030038294" "20030162342" "20030209717" "20030227065" "20040229429" "5807774" "5990500" "6100174" "6139780" "6284654" "6475321"). PN. OR ("6921928").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/10/31 19:58
S7	1147	372/43.01.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 20:49
S8	132	S7 and mesa and (ridge or stripe)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 20:50
S9	11	semiconductor near3 laser and current near3 injection near3 ridge and ((passivat \$3 or protect\$3) near3 (layer or coat\$3 or film)) and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 22:19
S10	4	semiconductor near3 laser and mesa and smooth near3 cleavage	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 22:13
S11	21	semiconductor near3 laser and smooth near3 cleavage	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 22:17
S12	8	"372"/\$.cds. and smooth near3 cleavage	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 22:17
S13	407	semiconductor near3 laser and ridge and ((passivat\$3 or protect\$3) near3 (layer or coat\$3 or film)) and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/11/01 19:36
S14	114	semiconductor near3 laser and ridge and ((passivat \$3) near3 (layer or coat\$3 or film)) and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/10/31 22:20
S15	205840	CAN NEAR3 SUBSTRATE	US-PGPUB; USPAT	OR	OFF	2006/11/01 17:48

S16	7576	CAN NEAR3 SEMI CONDUCTOR NEAR3 MATERIAL	US-PGPUB; USPAT	OR	OFF	2006/11/01 17:53
S17	364	S16 AND "372"/\$.CCLS.	US-PGPUB; USPAT	OR	OFF	2006/11/01 17:50
S18	7576	"CaN" NEAR3 SEMI CONDUCTOR NEAR3 MATERIAL	US-PGPUB; USPAT	OR	OFF	2006/11/01 17:50
S19	364	S18 AND "372"/\$.CCLS.	US-PGPUB; USPAT	OR	OFF	2006/11/01 17:51
S20	7	calcium near3 nitride near3 substrate	US-PGPUB; USPAT	OR	OFF	2006/11/01 17:52
S21	0	calcium near3 nitride NEAR3 SEMI CONDUCTOR NEAR3 MATERIAL	US-PGPUB; USPAT	OR	OFF	2006/11/01 17:53
S22	1	calcium near3 nitride NEAR3 SEMI CONDUCTOR	US-PGPUB; USPAT	OR	OFF	2006/11/01 17:54
S23	9	calcium near3 nitride and "372"/\$.ccls.	US-PGPUB; USPAT	OR	OFF	2006/11/01 17:54
S24	1	("5966396").PN.	US-PGPUB; USPAT	OR	OFF	2006/11/01 19:11
S25	204	nitride near3 laser and ridge and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/11/01 19:36
S26	293	nitride near3 laser and (ridge or stripe) and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/11/01 19:48
S27	12	nitride near3 laser and (ridge or stripe) and mesa and ((smooth\$3 or round \$3 or curv\$3) near3 (corner or cleavage))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2006/11/01 19:49
S28	2	((("5966396") or ("6444486"))).PN.	US-PGPUB; USPAT	OR	OFF	2007/05/01 16:26
S29	1	"372"/\$.ccls. and semiconductor near3 laser and ((scribing near3 force) with (prevent\$3 or reduc \$4))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/05/01 16:28
S30	1	semiconductor near3 laser and ((scribing near3 force) with (prevent\$3 or reduc \$4))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/05/01 16:29

S31	530	semiconductor near3 laser and rounded near3 corner	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/05/01 16:30
S32	2	semiconductor near3 laser and ((rounded near3 corner) with substrate) and ridge	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/05/01 16:31
S33	2	semiconductor near3 laser and ((rounded near3 corner) same substrate) and ridge	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/05/01 16:31
S34	5	semiconductor near3 laser and ((rounded near3 corner) and substrate) and ridge and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/05/01 16:31

EAST Search History (1 Interference)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L19	0	((rounded near3 corner and passivation and mesa and ridge).cm.	USPAT; UPAD	OR	ON	2010/10/11 11:39

10/ 11/ 10 11:40:20 AM**C:\Documents and Settings\arodriguez\ My Documents\ EAST\ Workspaces\ 10823653.wsp**